

## 长春新产业光电技术有限公司

Changehun New Industries Optoelectronics Tech. Co., Ltd.

DATA SHEET

## **EO-213-Subnano-Hi**/1~100μJ/1~500mW

## HIGH ENERGY DIODE PUMPED ALL-SOLID-STATE Q-SWITCHED LASER

High energy diode pumped all solid state Q-switched laser at 213nm has the features of high single pulse energy, short pulse duration, and high peak power, which is widely used in LIF, OPO, fluorescence lifetime measurement and so on.









## SPECIFICATIONS

Operating mode  Single pulse energy (uJ)  Output power (mW)  Power stability  Output power (mW)	13±1nm	
Single pulse energy (uJ) 40  Output power (mW) 20  Power stability <5	213±1nm	
Output power (mW) 20 Power stability <	Q-switched: EO (Electro-optic)	
Power stability <5	0uJ@5KHz	100uJ@5KHz
•	00	500
Pulse duration (ns)	5%	
	1.5ns@5KHz	~2ns@5KHz
Rep. rate (kHz)	100Hz~10kHz (Customized)	
Beam diameter (mm) ~1	~1.5mm	
Beam divergence, full angle (mrad) ≤3	≤3mrad	
Cooled method A	Air cooled@<2kHz; Water cooled@>2kHz	
Warm-up time (minutes) <1	<15	
Power supply De	DC 24V	
Operating temperature (°C)	15~30	
Expected lifetime (hours) 10	0000h	
Warranty period 1	year	







